

**2SA2073**

- 1) High speed switching. (  $t_f$  : Typ. : 20ns at  $I_c = -3A$  )
- 2) Low saturation voltage, typically.  
(Typ. : -200mV at  $I_c = -2.0A$ ,  $I_B = -200mA$  )
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Low Noise.
- 5) Complements the 2SC5826.

High speed switching, Low noise

## PNP silicon epitaxial planar transistor

Type	Package	Taping
	Code	TV2
	Basic ordering unit (pieces)	2500
2SA2073		○

Parameter	Symbol	Limits	Unit	
Collector-base voltage	$V_{CBO}$	−60	V	
Collector-emitter voltage	$V_{CEO}$	−60	V	
Emitter-base voltage	$V_{EBO}$	−6	V	
Collector current	DC	$I_C$	−3	A
	Pulsed	$I_{CP}$	−6	A *
Power dissipation	$P_C$	1.0	W	
Junction temperature	$T_j$	150	°C	
Range of storage temperature	$T_{stg}$	−55 to 150	°C	

\*Pw=10ms

**Dimensions (mm: inch)**

**ATV**

The diagram shows a mechanical drawing of the ATV package. It includes a top view and a side view. The top view shows a rectangular package with a width of 6.8 mm (0.27 inch) and a length of 14.5 mm (0.57 inch). The side view shows a height of 2.5 mm (0.1 inch) and a base width of 1.05 mm (0.04 inch). The package has three leads: (1) Emitter, (2) Collector, and (3) Base. The leads are spaced 2.54 mm (0.1 inch) apart. The maximum lead length is 0.65 mm (0.025 inch). The package is labeled with dimensions in mm and inches.

(1) Emitter  
(2) Collector  
(3) Base

Taping specifications

Abbreviated symbol : A2073

## Transistors

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	$BV_{CEO}$	-60	—	—	V	$I_C = -1\text{mA}$
Collector-base breakdown voltage	$BV_{CBO}$	-60	—	—	V	$I_C = -100\mu\text{A}$
Emitter-base breakdown voltage	$BV_{EBO}$	-6	—	—	V	$I_E = -100\mu\text{A}$
Collector cut-off current	$I_{CBO}$	—	—	-1.0	$\mu\text{A}$	$V_{CB} = -40\text{V}$
Emitter cut-off current	$I_{EBO}$	—	—	-1.0	$\mu\text{A}$	$V_{EB} = -4\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	-200	-500	mV	$I_C = -2.0\text{A}$ $I_B = -200\text{mA}$ *1
DC current gain	$h_{FE}$	120	—	270	—	$V_{CE} = -2\text{V}$ $I_C = -100\text{mA}$
Transistor frequency	$f_T$	—	200	—	MHz	$V_{CE} = -10\text{V}$ $I_E = 100\text{mA}$ $f = 10\text{MHz}$ *1
Collector output capacitance	$C_{ob}$	—	40	—	pF	$V_{CB} = -10\text{V}$ $I_E = 0\text{mA}$ $f = 1\text{MHz}$
Turn-on time	$t_{on}$	—	20	—	ns	$I_C = -3\text{A}$ $I_{B1} = -300\text{mA}$ $I_{B2} = 300\text{mA}$ $V_{CC} = -25\text{V}$ *2
Storage time	$t_{stg}$	—	130	—	ns	
Fall time	$t_f$	—	20	—	ns	

\*1 Single pulse

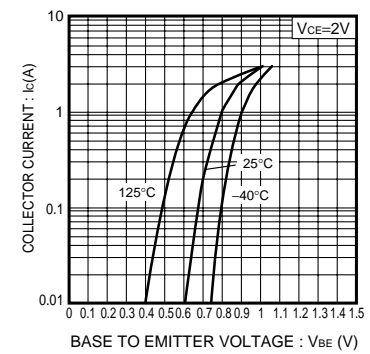
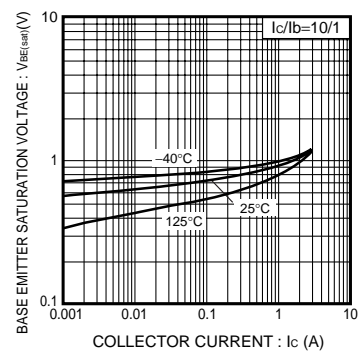
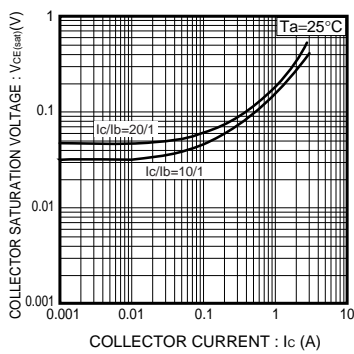
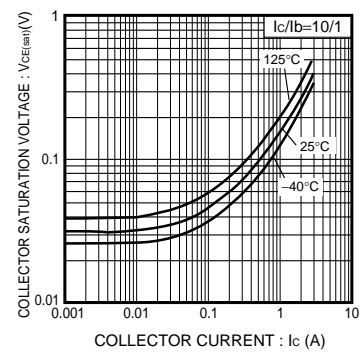
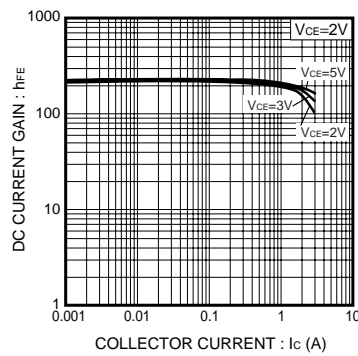
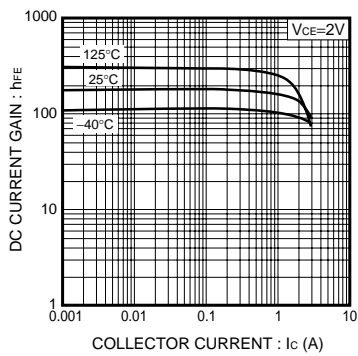
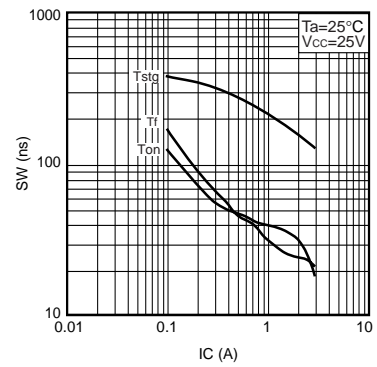
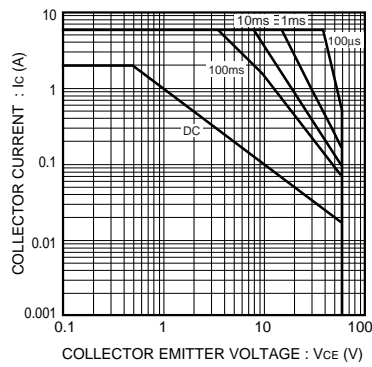
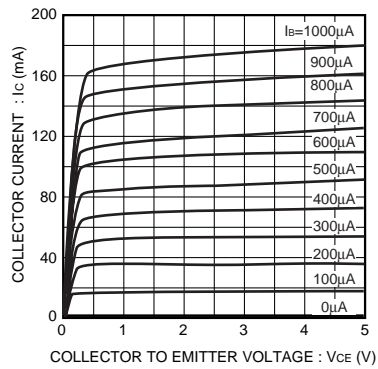
\*2 See switching characteristics measurement circuits

● $h_{FE}$  RANK

Q
120-270

## Transistors

## ●Electrical characteristics curves



## Transistors

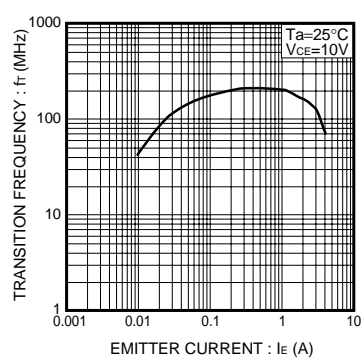


Fig.10 Transition frequency

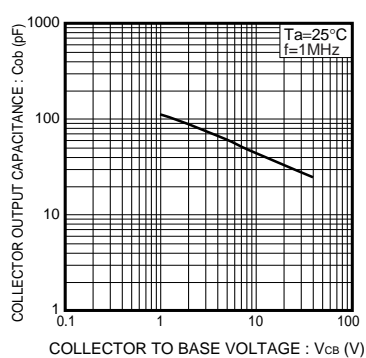
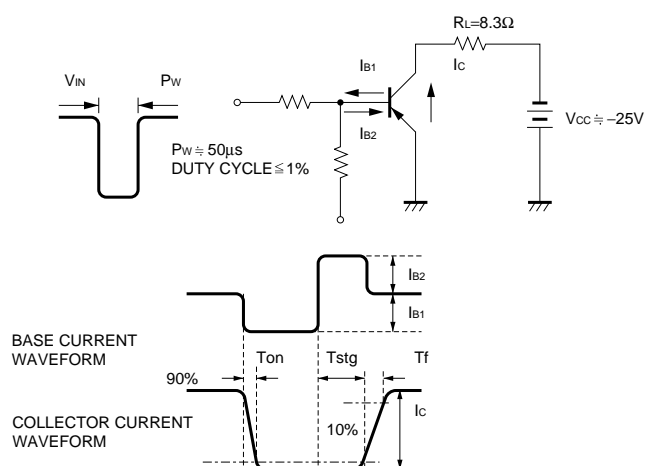


Fig.11 Collector output capacitance

## ●Switching characteristics measurement circuits



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